

## T493B336K010CH6310

Aliases (DLA Drawing 07016-037KCHB)

T493 HRA, Tantalum, MnO2 Tantalum, HRA, 33 uF, 10%, 10 VDC, SMD, MnO2, Molded, DLA Drawing, C (0.01%/1000 Hrs), 3.5 Ohms, 3528, 2.1 mm, 0.8 mm



Click [here](#) for the 3D model.

### General Information

Series	T493 HRA
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, DLA Drawing
RoHS	No
Prop 65	<b>WARNING:</b> Cancer and reproductive harm - <a href="https://www.p65warnings.ca.gov/">https://www.p65warnings.ca.gov/</a>
SCIP Number	1dd2e1b8-26dd-4d52-927c-6f9d519011aa
Termination	Tin Lead (SnPb)
AEC-Q200	No
Typical Component Weight	102.3 mg

### Dimensions

L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
H	1.9mm +/-0.2mm
S	0.8mm +/-0.3mm
F	2.2mm +/-0.1mm

### Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	2000

### Specifications

Capacitance	33 uF
Tolerance	10%
Voltage DC	10 VDC (85C), 6.7 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	C (0.01%/1000 Hrs)
ESR	3.5 Ohms (100kHz 25C)
Ripple Current	376 mA (rms, 100kHz 25C)
Leakage Current	3.3 uA (5min 25°C)
Testing and Reliability	10 Cycles Surge Current Testing At -55C And +85C After Weibull

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